

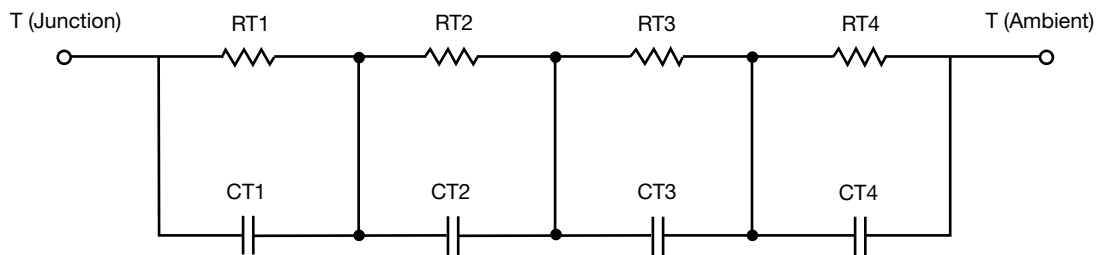
R-C Thermal Model Parameters

DESCRIPTION

The parametric values in the R-C thermal model have been derived using curve-fitting techniques. R-C values for the electrical circuit in the Foster/tank and Cauer/filter configurations are included. When implemented in P-SPICE, these values have matching characteristic curves to the single-pulse transient thermal impedance curves for the MOSFET.

These RC values can be used in the P-SPICE simulation to evaluate the thermal behavior of the MOSFET junction temperature under a defined power profile. These techniques are described in application note AN609, "Thermal Simulation of Power MOSFETs on the P-SPICE Platform".

R-C THERMAL MODEL FOR TANK CONFIGURATION



R-C VALUES FOR TANK CONFIGURATION			
THERMAL RESISTANCE (°C/W)			
Junction to	Ambient	Case	Foot
RT1	42.5172	N/A	10.4622
RT2	9.8002	N/A	4.3569
RT3	33.2456	N/A	8.0217
RT4	44.4370	N/A	26.6506
THERMAL CAPACITANCE (Joules/°C)			
Junction to	Ambient	Case	Foot
CT1	2.4220	N/A	3.9592m
CT2	397.5835u	N/A	459.3946u
CT3	130.3693m	N/A	520.4369m
CT4	3.6403m	N/A	4.9100m

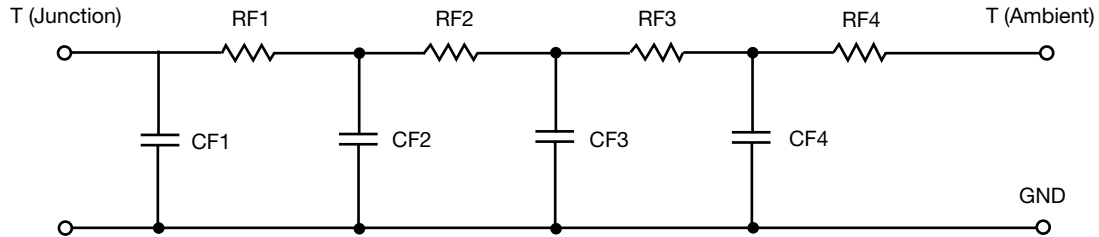
Note

N/A indicates not applicable

This document is intended as a SPICE modeling guideline and does not constitute a commercial product datasheet. Designers should refer to the appropriate datasheet of the same number for guaranteed specification limits.



R-C THERMAL MODEL FOR FILTER CONFIGURATION



R-C VALUES FOR FILTER CONFIGURATION			
THERMAL RESISTANCE (°C/W)			
Junction to	Ambient	Case	Foot
RF1	12.6113	N/A	5.1631
RF2	36.8847	N/A	16.8005
RF3	37.2257	N/A	20.4533
RF4	43.2783	N/A	7.3127
THERMAL CAPACITANCE (Joules/°C)			
Junction to	Ambient	Case	Foot
CF1	405.6089u	N/A	376.5842u
CF2	2.7183m	N/A	1.3904m
CF3	64.3923m	N/A	3.4283m
CF4	2.0419	N/A	753.5436m

Note
N/A indicates not applicable

